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Preparation, characterization, and giant dielectric permittivity of (Y^{3+} and Nb^{5+}) co-doped TiO_2 ceramics

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ABSTRACT

The microstructure and giant dielectric properties of Y^{3+} and Nb^{5+} co-doped TiO_2 ceramics prepared via a chemical combustion method are investigated. A main rutile- TiO_2 phase and dense ceramic microstructure are obtained in $(\text{Y}_{0.5}\text{Nb}_{0.5})_x\text{Ti}_{1-x}\text{O}_2$ ($x = 0.025$ and 0.05) ceramics. Nb dopant ions are homogeneously dispersed in the microstructure, while a second phase of Y_2O_3 particles is detected. The existence of Y^{3+} , Nb^{5+} , Ti^{4+} and Ti^{3+} as well as oxygen vacancies is confirmed by X-ray photoelectron spectroscopy and X-ray absorption near edge structure analysis. The sintered ceramics exhibit very high dielectric permittivity values of 10^4 – 10^5 in the frequency range of 40– 10^6 Hz. A low loss tangent value of ≈ 0.08 is obtained at 40 Hz. $(\text{Y}_{0.5}\text{Nb}_{0.5})_x\text{Ti}_{1-x}\text{O}_2$ ceramics can exhibit non-Ohmic behavior. Using impedance spectroscopy analysis, the giant dielectric properties of $(\text{Y}_{0.5}\text{Nb}_{0.5})_x\text{Ti}_{1-x}\text{O}_2$ ceramics are confirmed to be primarily caused by interfacial polarization.

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1. Introduction

Giant dielectric oxides are material that exhibit very large dielectric permittivity (ϵ') values, on the order of 10^3 – 10^6 , in the radio frequency range. These oxides have had a great impact on the progress made in recent years in the electronics industry, especially in high-energy-density storage devices. Many kinds of giant dielectric materials (e.g., oxides in a family of $\text{ACu}_3\text{Ti}_4\text{O}_{12}$ (where the A-site is occupied by cations with an average valance of +2) [1–5], $\text{AFe}_{1/2}\text{B}_{1/2}\text{O}_3$ (A = Ba, Sr, Ca; B = Nb, Ta, Sb) [6–8], and $\text{La}_{2-x}\text{Sr}_x\text{NiO}_4$ [9–11] among others) were discovered and have been intensively investigated. All giant dielectric oxides show fascinating dielectric behaviors, and studies of their properties have led to insights into their underlying mechanisms. Both classical and elegant new models have been proposed to answer questions about why these oxides show giant dielectric behaviors. These models include the internal or surface barrier layer capacitor model (IBLC or SBLC) [4,12–15], nano-barrier layer capacitor model [16], small polaron hopping

model [9,11], and the mixed-valent structure model [3,17] as well as the non-Ohmic sample-electrode contact model [15].

Unfortunately, unacceptably large values of the loss tangent ($\tan\delta$) of these giant dielectric oxides are one of their most serious drawbacks. Most recently, a promising giant dielectric oxide for future practical applications was reported in an In + Nb co-doped rutile- TiO_2 (INTO) ceramic [18]. INTO ceramics exhibited extremely high ϵ' values of more than 10^4 , depending on the dopant concentration. Notably, $\tan\delta$ of INTO ceramics was very low compared to those of other giant dielectric oxides. For example, doping TiO_2 with 10% (In + Nb) can result in values of $\epsilon' \approx 6 \times 10^4$ and $\tan\delta \approx 0.02$ [18]. In addition to the models above, the electron – pinned defect – dipole (EPDD) model was suggested as an explanation of the fascinating giant-dielectric properties of INTO ceramics. According to the EPDD model, the aliovalent dopants used (Nb^{5+} and In^{3+}) had a distinct function. The former, with higher valence state, was used to produce free electrons in the rutile- TiO_2 structure. The latter, with a lower valence state, was used to form local complex defect clusters that could confine free electrons [18]. It was further suggested that EPDDs can be produced in other co-doped TiO_2 systems [19,20]. This discovery has greatly stimulated research in the field of giant dielectric oxides [12,14,15,19–30]. In addition to the EPDD model,

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several studies have demonstrated that the giant dielectric properties of INTO ceramics originated from the IBLC or SBLC effect [13,15,23,25,27,29].

Several co-doped TiO_2 systems were synthesized and their giant dielectric properties reported. The aliovalent co-dopants studied were $\text{Ga}^{3+} + \text{Nb}^{5+}$ [12], $\text{Bi}^{3+} + \text{Nb}^{5+}$ [19], $\text{Al}^{3+} + \text{Nb}^{5+}$ [22], $\text{Bi}^{3+} + \text{Sb}^{5+}$ [30], and $\text{Sm}^{3+} + \text{Nb}^{5+}$ [20], among others. All of these co-doped TiO_2 systems showed very interesting giant dielectric behaviors. Various methodologies were used to clarify the origin of giant dielectric properties. From the point of view of capacitor applications, there is an ongoing need for a new system of co-doped TiO_2 . Although the giant dielectric properties of many co-doped TiO_2 systems have been reported, we think that it is worthwhile to develop a new co-doped TiO_2 system to increase the number of design options and to support a variety of applications. Thus, in the current work, a new system of (Y + Nb) co-doped TiO_2 was synthesized. The phase composition and microstructure were carefully characterized. The giant dielectric and nonlinear current density–electric field (J – E) properties of (Y + Nb) co-doped TiO_2 ceramics were investigated. Interestingly, very large ϵ' values were achieved in this new co-doped TiO_2 system. Interestingly, sintered ceramics can exhibit J – E characteristics. The origin of the giant dielectric response is also discussed in detail.

2. Experimental details

2.1. Ceramic preparation

$(\text{Y}_{1/2}\text{Nb}_{1/2})_x\text{Ti}_{1-x}\text{O}_2$ ceramics with $x=0.025$ and 0.05 (referred as 2.5%YNTO and 5.0%YNTO ceramics, respectively) were prepared using a combustion method with glycine as a fuel. $\text{C}_{16}\text{H}_{28}\text{O}_6\text{Ti}$ (Sigma–Aldrich), $\text{Y}(\text{NO}_3)_3 \cdot 6\text{H}_2\text{O}$ (Kento Chemical, >99.99%), NbCl_5 (Sigma–Aldrich, >99.9%), deionized water, citric acid, and glycine were used as the starting raw materials. Details of the preparation method are similar to those reported for preparation of $(\text{In}_{1/2}\text{Nb}_{1/2})_x\text{Ti}_{1-x}\text{O}_2$ ceramics [15]. First, $\text{Y}(\text{NO}_3)_3 \cdot 6\text{H}_2\text{O}$ and NbCl_5 were dissolved in an aqueous solution of citric acid with constant stirring at room temperature (RT). Second, a $\text{C}_{16}\text{H}_{28}\text{O}_6\text{Ti}$ solution was added into the solution above until a clear and transparent solution can be observed. Third, glycine powder was mixed into the metal ion solution with stirring at 150°C until a viscous gel was obtained. Then, the gel was dried at 350°C for 1 h using heating rate $1^\circ\text{C}/\text{min}$. Next, the resulting dried precursors were calcined in air at 1000°C for 6 h. The powders obtained after calcination were pressed under uniaxial compression at $\approx 200\text{ MPa}$ into pellets that were 9.5 mm in diameter and $\sim 1.5\text{ mm}$ in thickness. Finally, ceramic samples with dense ceramic microstructure and no porosity were achieved by sintering in air at 1500°C for 2 h with heating and cooling rates $2^\circ\text{C}/\text{min}$.

2.2. Characterizations

The phase composition and crystal structure of the ceramic samples were characterized using X-ray diffraction (PANalytical, EMPYREAN). The microstructure of sintered ceramics was characterized using field-emission scanning electron microscopy (FE–SEM) with energy-dispersive X-ray analysis (EDS) (HITACHI SU8030, Japan). The as-fired $(\text{Y}_{1/2}\text{Nb}_{1/2})_x\text{Ti}_{1-x}\text{O}_2$ ceramics were carefully polished. Then, an obvious grain and grain boundary (GB) structure of the polished samples was accomplished by thermally etching at 1100°C for 30 min. Polished and etched surface was characterized by a scanning electron microscopy (SEM) (SEC, SNE4500 M). The chemical states of sintered $(\text{Y}_{1/2}\text{Nb}_{1/2})_x\text{Ti}_{1-x}\text{O}_2$ ceramics were analyzed using X-ray Absorption Near Edge Structure (XANES) and X-ray photoelectron spectroscopy (XPS, PHI5000

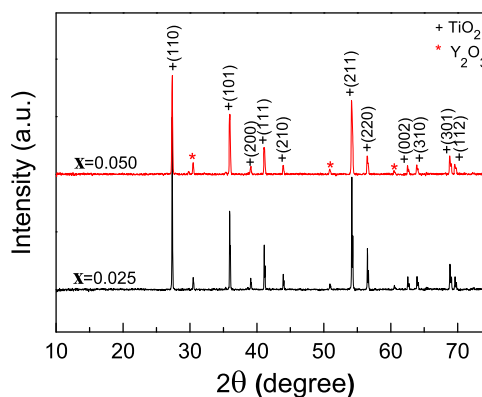


Fig. 1. XRD patterns of $(\text{Y}_{1/2}\text{Nb}_{1/2})_x\text{Ti}_{1-x}\text{O}_2$ ceramics with $x=0.025$ (2.5%YNTO) and 0.05 (5.0%YNTO).

VersaProbe II, ULVAC–PHI, Japan). XANES and XPS spectra were, respectively, collected at the SUT–NANOTEC–SLRI XAS beam-line (BL5.2) (electron energy of 1.2 GeV ; bending magnet; beam current $80\text{--}150\text{ mA}$; $1.1\text{ to }1.7 \times 10^{11}\text{ photon s}^{-1}$) and at the SUT–NANOTEC–SLRI Joint Research Facility, the Synchrotron Light Research Institute (SLRI), Nakhon Ratchasima, Thailand. Detail of the XANES characterization technique are given elsewhere [31]. The XPS spectra were fitted with PHI MultiPak XPS software using a combination of Gaussian–Lorentzian lines.

2.3. Dielectric and electrical measurements

For dielectric and electrical measurements, Au was sputtered onto both pellet faces at a current of 25 mA for 8 min using a Polaron SC500 sputter coating unit. The capacitance (C_p) and dissipation factor (D or $\tan\delta$) were measured using a KEYSIGHT E4990A Impedance Analyzer over the frequency and temperature ranges of $40\text{--}10^6\text{ Hz}$ and $-50\text{--}200^\circ\text{C}$, respectively. Each measurement temperature was held constant with a precision of $\pm 0.1^\circ\text{C}$ with an oscillation voltage of 0.5 V . The nonlinear current density–electric field (J – E) behavior at RT was measured using a high voltage measurement unit (Keithley Model 247). E_b was defined as the electric field breakdown strength at which $J=1\text{ mA}/\text{cm}^2$. The nonlinear coefficient (α) was calculated in the range of $J=1\text{--}10\text{ mA}/\text{cm}^2$.

3. Results and discussion

Fig. 1 shows the XRD patterns of the sintered 2.5%YNTO and 5.0%YNTO ceramics. Both of the ceramic samples show a main phase consisting of rutile– TiO_2 (JCPDS 21–1276) with a tetragonal structure. A second phase of Y_2O_3 is observed in the XRD patterns of these two samples. Lattice parameters (a and c values) were calculated. a values of the 2.5%YNTO and 5.0%YNTO ceramics are, respectively, 4.596 ± 0.001 and 4.598 ± 0.003 , while c values are 2.963 ± 0.001 and 2.965 ± 0.003 , respectively. The a and c values of both YNTO ceramics increase with increasing co-dopant concentration. Lattice parameters of both of the YNTO ceramics are larger than the a (4.593 \AA) and c (2.959 \AA) values of the pure rutile– TiO_2 (JCPDS 21–1276). The enhancement of the lattice parameters may be attributed to the larger ionic radii of Y^{3+} ($r_6=0.90\text{ \AA}$) and Nb^{5+} ($r_6=0.64\text{ \AA}$) than that of the host Ti^{4+} ion ($r_6=0.605\text{ \AA}$) [32]. With regard to the low dopant concentrations of Nb^{5+} (1.25–2.5 at%) in both YNTO ceramics, Nb^{5+} dopant ions can often completely enter into Ti^{4+} sites in the rutile structure [18]. However, a secondary Y_2O_3 phase was detected indicating that some portion or all of the Y^{3+} could not be substituted into the Ti^{4+} sites. Considering the greatly increased a and c values, it is likely that only some portion of the Y^{3+} ions were substituted into the TiO_2 structure.

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